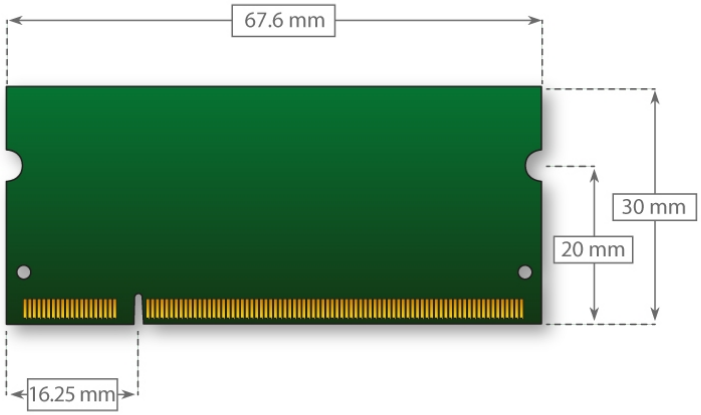
DRAM MEMORY MODULE SPECIFICATION

> Lifetime Warranty
> Delivered in Anti-Static Packaging



INTEGRAL Part Number	IN2V512NWEEX
Description	512MB DDR2 667MHz NOTEBOOK NON-ECC MEMORY MODULE
Category	NOTEBOOK
Form Factor	200pin SoDIMM
Density	512MB
DRAM Technology	DDR2
Speed	PC2-5300 / 667 MHz
Depth	64Mbit
Width	X64bit
Buffering	UNBUFFERED
Error Correction	NON-ECC
CAS Latency	5 CYCLES
Voltage	1.8 V
Rank	2
Profile	STANDARD
DRAM IC Configuration	32Mbit X 16bits
DRAM IC Count	8 Chips
DRAM IC Package	FBGA
DRAM IC Placement	SINGLE SIDED
Note	

Height of module may vary. Specifications subject to change without notice. 10-year warranty in Germany, France and Austria. All trademarks are property of their respective owners. Diagram for illustration only. E&OE